

IRFM220BTF_FP001

IRFM220BTF_FP001 Information



E-mail: salesdept@heisener.com

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IRFM220BTF_FP001 Specifications

Manufacturer Part Number	IRFM220BTF_FP001
Manufacturer	Fairchild/ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-261-4, TO-261AA
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	200V
Current - Continuous Drain (Id) @ 25°C	1.13A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	16nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	390pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	2.4W (Ta)
Rds On (Max) @ Id, Vgs	800 mOhm @ 570mA, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	SOT-223-4
Package / Case	TO-261-4, TO-261AA
	Report errors?

IRFM220BTF_FP001 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

IRFM220BTF_FP001 Payment Methods





If you have any question about IRFM220BTF_FP001, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com